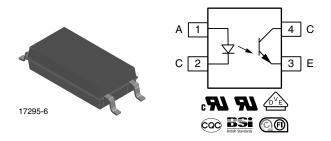
VOL617A



Vishay Semiconductors

Optocoupler, Phototransistor Output, 4 Pin LSOP, Long Creepage Mini-Flat Package



DESCRIPTION

The VOL617A has a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a 4 pin LSOP wide body package.

It features a high current transfer ratio, low coupling capacitance, and high isolation voltage.

The coupling device is designed for signal transmission between two electrically separated circuits.

FEATURES

Low profile package

- High collector emitter voltage, $V_{CEO} = 80 \text{ V}$
- Isolation test voltage, 5000 V_{BMS}
- Isolation voltage V_{IORM} = 1050 V_{peak}
- Low coupling capacitance
- High common mode transient immunity
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

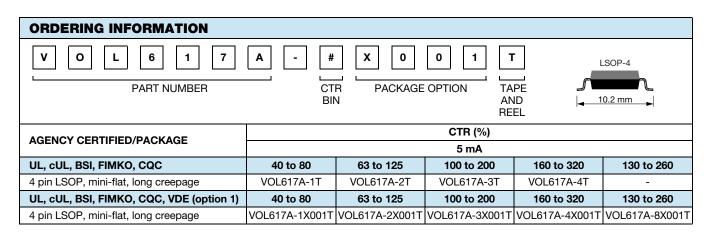
APPLICATIONS

- Telecom
- Industrial controls
- Battery powered equipment
- Office machines
- Programmable controllers

AGENCY APPROVALS

(All parts are certified under base model VOL617A)

- UL1577, file no. E76222
- cUL CSA 22.2 bulletin 5A, double protection
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- BSI: EN 60065:2002, EN 60950-1:2006
- FIMKO EN60950-1
- CQC: GB8898-2011, GB4943.1-2011



1





RoHS

COMPLIANT

HALOGEN

FREE

GREEN

(5-2008)



www.vishay.com

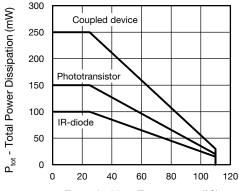
Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS (Tamb	= 25 °C, unless otherwise s	specified)			
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
INPUT		·			
Reverse voltage		V _R	6	V	
Power dissipation		P _{diss}	100	mW	
Forward current		I _F	60	mA	
Junction temperature		Тj	125	°C	
OUTPUT					
Collector emitter voltage		V _{CEO}	80	V	
Emitter collector voltage		V _{ECO}	7	V	
Collector current		Ι _C	50	mA	
Collector current	t _p /T = 0.5, t _p < 10 ms	Ι _C	100	mA	
Power dissipation		P _{diss}	150	mW	
Junction temperature		Тj	125	°C	
COUPLER					
Isolation test voltage between emitter and detector	t = 1 min	V _{ISO}	5000	V _{RMS}	
Total power dissipation		P _{tot}	250	mW	
Storage temperature range		T _{stg}	- 55 to + 125	°C	
Ambient temperature range		T _{amb}	- 55 to + 110	°C	
Soldering temperature ⁽¹⁾	≤ 10 s	T _{sld}	260	°C	

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices.



T_{amb} - Ambient Temperature (°C)

Fig. 1 - Total Power Dissipation vs. Ambient Temperature

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward voltage	I _F = 5 mA	V _F		1.16	1.5	V	
Capacitance	$V_R = 0 V$, f = 1 MHz	Co		45		pF	
Reverse current	V _R = 6 V	I _R			100	μA	
OUTPUT	OUTPUT						
Collector emitter leakage current	$V_{CE} = 10 \text{ V}, I_F = 0 \text{ A}$	I _{CEO}		10	200	nA	
Collector emitter capacitance	$V_{CE} = 5 V, f = 1 MHz$	C _{CE}		7		pF	
COUPLER							
Collector emitter saturation voltage	l _C = 1.0 mA, l _F = 5 mA	V _{CEsat}		0.25	0.4	V	
Coupling capacitance	f = 1 MHz	C _C		0.25		pF	

Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

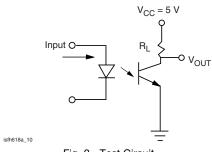
2



Vishay Semiconductors

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
$I_{\rm C}/I_{\rm F}$ $I_{\rm F} = 5$ mA, $V_{\rm CE} = 5$		VOL617A-1	CTR	40		80	%
		VOL617A-2	CTR	63		125	%
	$I_{F} = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	VOL617A-3	CTR	100		200	%
		VOL617A-4	CTR	160		320	%
		VOL617A-8	CTR	130		260	%

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn on time	V_{CC} = 5 V, I_C = 2 mA, R_L = 100 Ω	t _{on}		6		μs
Rise time	V_{CC} = 5 V, I_C = 2 mA, R_L = 100 Ω	t _r		3.5		μs
Turn off time	V_{CC} = 5 V, I_C = 2 mA, R_L = 100 Ω	t _{off}		5.5		μs
Fall time	V_{CC} = 5 V, I _C = 2 mA, R _L = 100 Ω	t _f		5		μs



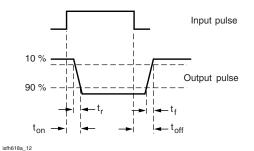


Fig. 2 - Test Circuit

Fig. 3 - Test Circuit and Waveforms

SAFETY AND INSULATION RATED PARAMETERS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Partial discharge test voltage - routine test	100 %, t _{test} = 1 s	V_{pd}	2			kV
Partial discharge test voltage -	t _{Tr} = 60 s, t _{test} = 10 s,	VIOTM	8			kV
lot test (sample test)	(see figure 4)	V _{pd}	1.68			kV
Insulation voltage		VIORM			1050	V _{peak}
Insulation resistance	$V_{IO} = 500 V_{DC}, T_{amb} = 25 \text{ °C}$	R _{IO}	10 ¹²			Ω
	$V_{IO} = 500 V_{DC}, T_{amb} = 100 \ ^{\circ}C$	R _{IO}	10 ¹¹			Ω
	V _{IO} = 500 V _{DC} , T _{amb} = 150 °C (construction test only)	R _{IO}	10 ⁹			Ω
Safety rating - maximum input current		I _{si}			130	mA
Safety rating - maximum power dissipation		P _{SO}			265	mW
Rated impulse voltage		VIOTM			8	kV
Safety rating - maximum ambient temperature		T _{si}			150	°C
Clearance distance			8			mm
Creepage distance			8			mm
Insulation distance (internal)			0.4			mm

Note

According to DIN EN 60747-5-5 (VDE 0884), § 7.4.3.8.2, (see figure 4). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.



300 Phototransistor P_{SO} (mW) 250 200 150 100 IR-diode I_{si} (mA) 50 0 150 0 25 50 75 100 125 T_{si} - Safety Temperature (°C) Fig. 4 - Derating Diagram

Vishay Semiconductors

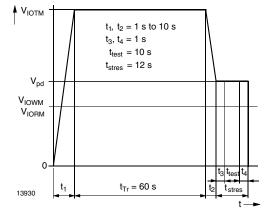


Fig. 5 - Test Pulse Diagram for Sample Test according to DIN EN 60747-5-5



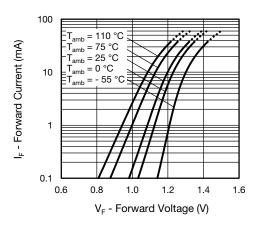


Fig. 6 - Forward Current vs. Forward Voltage

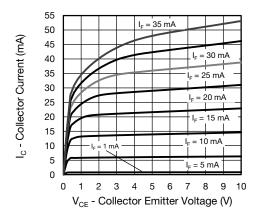


Fig. 7 - Collector Current vs. Collector Emitter Voltage

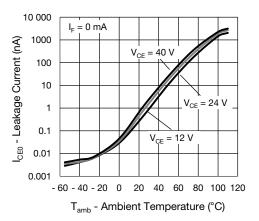


Fig. 8 - Collector Emitter Current vs. Ambient Temperature

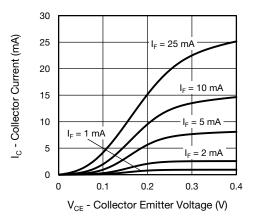
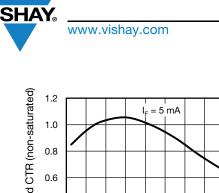


Fig. 9 - Collector Current vs. Collector Emitter Voltage

4

For technical questions, contact: <u>optocoupleranswers@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>





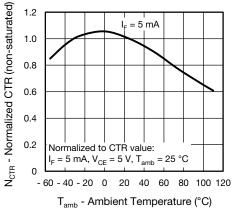


Fig. 10 - Normalized Current Transfer Ratio (non-sat) vs. Ambient Temperature

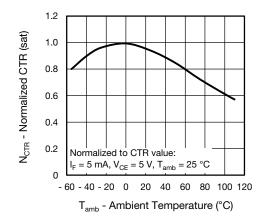


Fig. 11 - Normalized Current Transfer Ratio (sat) vs. Ambient Temperature

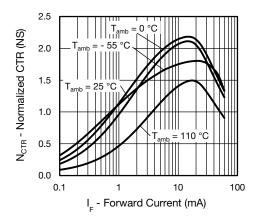


Fig. 12 - Normalized Current Transfer Ratio (non-sat) vs. Forward Current

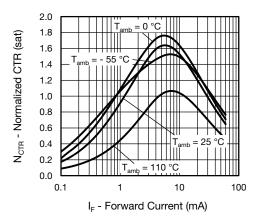


Fig. 13 - Normalized Current Transfer Ratio (sat) vs. Forward Current

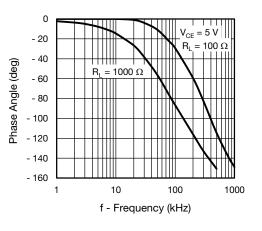


Fig. 14 - f_{CTR} vs. Phase Angle

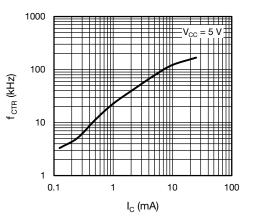


Fig. 15 - f_{CTR} vs. Collector Current

Rev.	1.7,	08-Oct-13
------	------	-----------

5

For technical questions, contact: optocoupleranswers@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Vishay Semiconductors

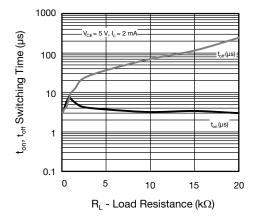


Fig. 16 - Switching Time vs. Load Resistance

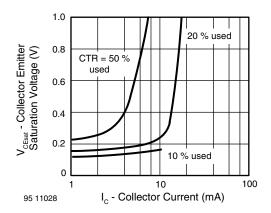


Fig. 17 - Collector Emitter Saturation Voltage vs. Collector Current

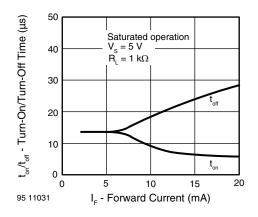
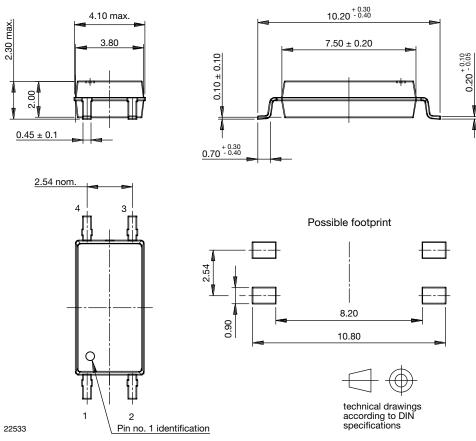


Fig. 18 - Turn-On/Turn-Off Time vs. Forward Current

Vishay Semiconductors

www.vishay.com

PACKAGE DIMENSIONS in millimeters



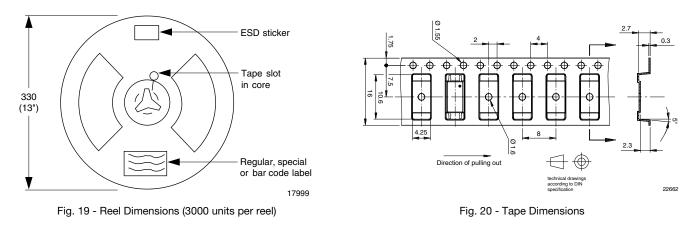
PACKAGE MARKING (example of VOL617A-3X001T)



Notes

- Only option 1 is reflected in the package marking with the characters "X1".
- Tape and reel suffix (T) is not part of the package marking.

TAPE AND REEL DIMENSIONS in millimeters



Rev. 1.7, 08-Oct-13

7

Document Number: 82424

For technical questions, contact: <u>optocoupleranswers@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.